Comparison of Radiation Damage in Lead Tungstate Crystals under Pion and Gamma Irradiation

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Abstract

Studies of the radiation hardness of lead tungstate crystals produced by the Bogoroditsk Techno-Chemical Plant in Russia and the Shanghai Institute of Ceramics in China have been carried out at IHEP, Protvino. The crystals were irradiated by a 40 GeV pion beam. After full recovery, the same crystals were irradiated using a $^{137}$Cs $\gamma$-ray source. The dose rate profiles along the crystal length were observed to be quite similar. We compare the effects of the two types of radiation on the crystals light output.

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1 Introduction

Lead tungstate (PbWO$_4$) crystals are planned for use in as the absorptive media in the electromagnetic calorimeters in some collider experiments. The crystals will be irradiated by high energy particles and accumulate significant absorbed doses, up to a several Mrad. The radiation hardness of PbWO$_4$ crystals has been studied by the CMS group using radioactive sources and electron beams [1] and by the BTeV group using both high energy pion and electron beams. A mixture of pion and electron beams provides a particle environment similar to that expected when running the BTeV experiment [2,3].

The goal of this study is to compare the radiation damage of crystals using two types of irradiation, either a high energy pion beam or a $^{137}$Cs radioactive source. If the effects of these two types of radiation are similar, we could use source measurements to classify the radiation resistance of each crystal in the BTeV like environment. This would be considerably easier than using particle beams for this measurement. Assessing the radiation resistance, is a crucial aspect of crystal quality assurance needed before assembling the electromagnetic calorimeter. However, until now, there has not been a comparative study of PbWO$_4$ crystal radiation damage under hadron beam and gamma source irradiation.

The expected dose distribution in the BTeV crystals is shown in Table 1 for a collider luminosity of $2 \times 10^{32}$ cm$^{-2}$s$^{-1}$ and a running time of $10^7$ s.

Table 1
Fraction of BTeV crystals with given absorbed doses and dose rates estimated at the maximum of the dose profiles inside the crystals (100 rad = 1 Gy)

<table>
<thead>
<tr>
<th>Relative number (%)</th>
<th>Absorbed dose (krad/year)</th>
<th>Dose rate (rad/h)</th>
</tr>
</thead>
<tbody>
<tr>
<td>33</td>
<td>0.3 - 2</td>
<td>0.11 - 0.72</td>
</tr>
<tr>
<td>27</td>
<td>2 - 5</td>
<td>0.72 - 1.8</td>
</tr>
<tr>
<td>12</td>
<td>5 - 10</td>
<td>1.8 - 3.6</td>
</tr>
<tr>
<td>16</td>
<td>10 - 50</td>
<td>3.6 - 18</td>
</tr>
<tr>
<td>6.2</td>
<td>50 - 100</td>
<td>18 - 36</td>
</tr>
<tr>
<td>3.2</td>
<td>100 - 200</td>
<td>36 - 72</td>
</tr>
<tr>
<td>2</td>
<td>200 - 500</td>
<td>72 - 180</td>
</tr>
<tr>
<td>0.4</td>
<td>500 - 1000</td>
<td>180 - 360</td>
</tr>
<tr>
<td>0.2</td>
<td>1000 - 2000</td>
<td>360 - 720</td>
</tr>
</tbody>
</table>

Since the BTeV calorimeter starts close to the beam-line, about 15 cm away, and extends to a radius of 160 cm, the amount of radiation varies greatly. Near the beam-line a small fraction of the crystals, $\sim$1% have doses of about $10^4$ Gy (1 Mrad), while 90% of the crystals have doses less than 0.1 Mrad. The latter corresponds to a dose rate of 36 rad/h.
About 70% of the crystals have dose rates < 4 rad/h.

We used three crystals produced by the Bogoroditsk Techno-Chemical Plant in Russia (denoted as CMS-2442, CMS-2443, Bogo-2313 ) and three more crystals produced by the Shanghai Institute of Ceramics in China (denoted as Shan-T16, Shan-T19, Shan-T20 ). All the crystals except those which are marked as CMS were produced at the end of 2000. The CMS crystals were produced in 2001. The dimensions of the crystals were \( \sim 27 \times 27 \) mm\(^2\) in cross section and 220 mm in length. The CMS crystals had the same length but were tapered; the dimension at the back is \( 29 \times 29 \) mm\(^2\). Each crystal was wrapped using 170 \( \mu \text{m} \) thick Tyvek.

The crystals were irradiated by a 40 GeV \( \pi^- \) beam, four of them in April 2001 and the other two, the CMS crystals, in April 2002. After the recovery process at room temperature the crystals were irradiated by \(^{137}\text{Cs} \gamma\)-source in May and June 2003. We provided very similar irradiation conditions, in terms of dose rates and absorbed doses, for both cases. Two types of measurements were done on each crystal both before and after the gamma irradiation: a) light output (LO) measurements using a radioactive source for crystal excitation, and b) crystal transparency measurements using a spectrophotometer.

2 Irradiation by pions

Pion irradiation was carried out at the IHEP (Protvino) 70 GeV accelerator. The size of the 40 GeV \( \pi^- \) beam was 8 cm horizontally and 6 cm vertically, \( i.e. \) 90% of the beam was contained within these dimensions. The beam was present in 1.2 second interval of the full accelerator cycle of 9 sec. Six crystals were irradiated with a dose rate ranging from 30 to 60 rad/h. The crystals light output signals were monitored using the minimum ionizing particles (MIP) in pion beam running and from separate low-intensity calibration runs in electron beam running. LeCroy 2285 15-bit integrating ADC’s were used to measure the signal using a 150 ns integration time. The Protvino testbeam setup is described in detail elsewhere [3,4,5].

3 Irradiation using a \(^{137}\text{Cs} \) source

We used a radioactive source \(^{137}\text{Cs} \), that emits 661 KeV photons and had an activity of \( 5 \cdot 10^{12} \) Bq to irradiate the crystals. The geometrical setup for each crystal position is shown in Fig. 1. Each crystal was irradiated separately. A commercial dosimeter, DKS-AT1123, was used to measure the dose rate (in air) in proximity to the crystals. The accuracy is better than 25% [6].

To modify the spatial dose distribution from the source in order to make it as similar as possible to pion beam, we used a lead screen placed between the source and the crystals.
and also rotated the crystals along their longitudinal axes at a rate of 2 turns per minute. The lead screen was made using four lead plates with varying dimensions [7]. The dose rate distributions along the length of crystal are compared for both the pion and source irradiation in Fig. 2 using the lead screen and rotating the crystals. We see that the profiles are quite similar. The rotation is even more important for insuring a uniform irradiation transverse to the crystal axis when using the source. In Fig. 3 we show the transverse radiation profiles for case (a) where the crystal was not rotated and for case (b) where it was rotated. Since pion irradiation uniformly illuminates the crystals in transverse direction, we use the crystal rotation for all the source results in this paper. The MARS and ROZ-6 codes were used for simulations of the dose profiles in crystal under pion and gamma irradiation respectively [3,8].

Two sets of gamma irradiation were carried out. One of them was done using dose rates of (30-60) rad/h, and the second one at the dose rate of 110 rad/h for each crystal. The crystals were allowed to recover during two weeks, at room temperature, between the first and the second sets of irradiation. After each exposition the crystal was removed.
Fig. 2. Longitudinal dose rate profiles for crystal under pion and gamma irradiation (Z near 22 cm corresponds to the phototube front).

Fig. 3. Transverse dose rate profiles for crystal under $^{137}$Cs gamma irradiation: a) side irradiation without crystal rotation, b) side irradiation with crystal rotation. Dose estimations were made in both “air” and “crystal,” as indicated.

from the place of irradiation to dedicated test stands for light output and transmittance measurements. This procedure usually took about 1 to 1.5 hours.

4 Light output and transmittance measurements

A stand with a radioactive source was used to study changes in the crystal light output due to radiation damage. Scintillation light was detected by a XP2020Q photomultiplier tube (PMT). The PMT output was connected to a 20 kOhm load. The mean current
through this load was measured by a 11-bit ADC read out by a computer. The PMT high voltage value was of 1.5 kV. The PMT nonlinearity in the direct current mode was less than 1% in the range of 1.2 kV to 2 kV. The dark current was $\sim 2 \cdot 10^{-3}$ relative to the average signal level. The background current, mostly due to direct PMT irradiation by the source was $\sim 5 \cdot 10^{-3}$ of the average signal in the worst instance. A $^{137}$Cs source ($7 \cdot 10^8$ Bq) was installed inside a cylindrical lead collimator, 30 mm in diameter and 40 mm in height with aperture diameter of 5.3 mm. The crystals were wrapped by a Tyvek, except for one end which was attached to the PMT without optical grease. The source was moved longitudinally parallel to the central line of the crystal with steps of 2 cm. The distance between the source and the crystal surface was 5 mm. The measurements of the average direct current were provided in the same way for each of the 9 position along the crystal. The mean value over these 9 measurements gives us a value of a light output signal of each crystal. The light output measurements were monitored using a non-irradiated reference crystal. Performing measurements on non-irradiated crystals, we estimate the systematic error to be at most 3% of the relative light output degradation. The temperature was measured during irradiation and during light output monitoring. The temperature variations were $\sim 1$ degree on average, and up to 2 degrees in the worst case. There were no corrections for the temperature variations. The full systematic errors of the monitoring measurements include the effects of the temperature differences.

To measure the light transmittance of each crystal, a commercial spectrophotometer SF-26 was used in the wavelength region from 340 up to 700 nm with a steps of 10 nm. The spectrophotometer light spot was 5 mm in diameter with a negligible angular dispersion. The measurement accuracy at each point was 1%.

### 5 Results and discussion

The dependence of a signal loss on the accumulated dose (at a fixed dose rate) for six crystals irradiated by $^{137}$Cs source is shown in Fig. 4. Two crystals lost 10% of their signal or less under the source irradiation and four other crystals lost (15-25)%. The light loss in transmittance curves at wavelengths of (420-550) nm measured with the use of the spectrophotometer is one order of magnitude less. For example crystal CMS-2442 showed losses between 2-2.5% (see Fig. 5). This difference might be due to different optical paths in crystal taken by the injected spectrophotometer light as compared with the scintillation light. From now on we will show only the results from the radioactive source measurements which are more sensitive than the spectrophotometer measurements in showing the effects of radiation.

It has been shown that PbWO$_4$ transmission damage occurs in the crystal when valence electrons are trapped in metastable states around crystal defects. Thus, the irradiation of PbWO$_4$ crystals creates so called color centers which reduce the light attenuation length. When the rate of color centers production (proportional to the dose rate) equals the natural recovery rate, the crystal light output will reach a saturation level [9]. Fig. 4 shows that the signal degrades relatively rapidly with the absorbed dose up to (100-200) rad and then degrades at a significantly slower rate until the saturation level is reached.
Fig. 4. Light output loss for six crystals versus absorbed dose under gamma irradiation at a fixed dose rate for each crystal. There were several measurements for the two crystals, CMS-2443 and Bogo-2313 (upper part). The results of measurements for other four crystals (bottom part) are consistent with the first two, but were taken at longer intervals.

Fig. 5. Transmittance of the CMS-2442 crystal before (open circles) and after (filled circles) gamma irradiation at 41 rad/h dose rate and 4.4 krad of absorbed dose.

The light loss has a tendency to exhibit saturation when the dose rate is kept at a constant level. Each crystal demonstrates a different level of light loss in the saturated state. We found that the saturation level is reliably reached after \(~\)10 hours of continuous irradiation at the fixed dose rate. We did not observe a significant difference in radiation hardness of the crystals from different manufacturers.

The second round of gamma irradiation was done at a dose rate of 110 rad/h for each crystal, after two weeks of recovery at room temperature. Because we irradiated the
Fig. 6. Dependence of the normalized light output loss (in state of saturation) on a dose rates for six crystals for gamma irradiation using $^{137}$Cs source.

crystals with 110 rad/h gamma-source for a long time, $\sim$(60-70) hours, we believe that we reached the signal loss saturation level for each crystal at this high dose rate. The dependence of the normalized signal loss (in state of saturation) on the dose rate for the six crystals under gamma irradiation is shown in Fig. 6.

The normalized signal loss versus of the absorbed dose under 40 GeV pion irradiation for the same crystals is presented in Fig. 7. The points on the plot represent the level of signal loss after saturation was reached at the specified fixed dose rates. The rate of the
signal degradation is practically the same for both irradiation procedures up to the dose rates of 60 rad/h. Using gamma irradiation at a dose rate of 110 rad/h does not lower the saturation level of some of the crystals, while others are affected (see Fig. 6). This is an indication that the relative difference of the crystal signal losses demonstrated at dose rates of 30-60 rad/h might change at larger dose rates.

Ratios of pion/gamma signal losses at saturation, caused by irradiation at the same dose rates, for the six crystals are shown in Fig. 8. We see that these ratios are close to each other and are in the region between 0.8 and 1. Thus we can conclude that pion and gamma irradiation at the same dose rates affect lead tungstate crystals in a similar fashion.

We intend to continue our studies; we want to carry out crystal radiation studies for significantly larger numbers of crystals while making continuous light output measurements during the gamma irradiation process.

6 Summary

We have observed that the relative signal loss using 40 GeV pion irradiation and using $^{137}$Cs radioactive source irradiation looks similar at the dose rate of (30-60) rad/h.

We have shown that the gamma-source can be used to evaluate the radiation tolerance of PbWO$_4$ crystals. It takes approximately 10 hours of irradiation at fixed dose rates to reach a saturation plateau for each crystal. The dose rate can be chosen in the range of (60-100) rad/h because the most of the crystals will be suffering from the lower dose rates at the BTeV experiment.
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[7] The lead screen was formed of plates with dimensions (thickness, length, height)xmm$^3$: 19x20x40, 12x20x50, 7.5x20x50 and 2x30x50.
